DS04-28206-2E

# **ASSP**

# 1 Channel 8-bit A/D Converter

# **MB40528**

#### DESCRIPTION

The MB40528 is a full parallel comparison (flash) type 8-bit resolution analog-to-digital converter, designed for various video and image processing applications.

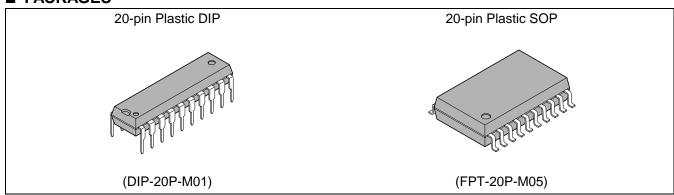
The MB40528 has 8-bit resolution 1 channel A/D converter. Input analog data are converted into digital data by the A/D converter in minimum 60 Mega samples per seconds (MSPS).

The analog data is provided in a range of DC +3V to +5V (2Vp-p level) and the output digital data in TTL level. The MB40528 is fabricated by the Fujitsu's advanced bipolar process and housed in a 20-pin plastic DIP/SOP. The MB40528 is suitable for various video and image applications.

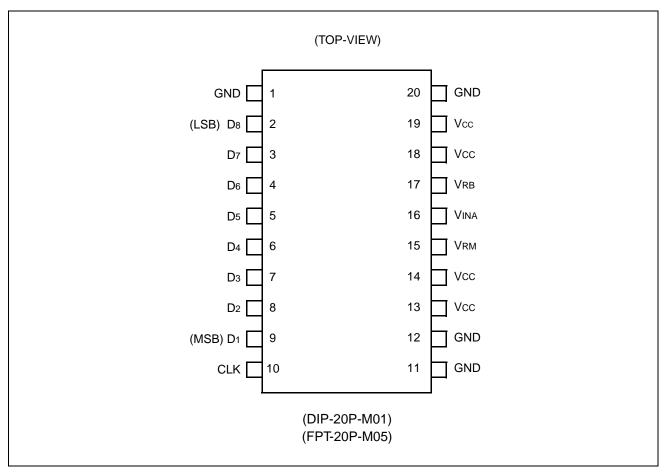
#### **■ FEATURES**

- Conversion method : Full parallel comparison type
- 8-bit x 1 channel A/D converter
- Max. 60 MHz input clock frequency providing 60 MSPS data conversion rate
- Linearity error : Typical +/-0.15%
- Analog input voltage range: 3V to 5V (2Vp-p level)
- Digital input/output voltage level : TTL level
- · On-chip reference voltage generator
- Low power consumption: Typical 400mW
- Single +5V power supply
- Operating temperature range : -20°C to +70°C
- Fujitsu's advanced bipolar process

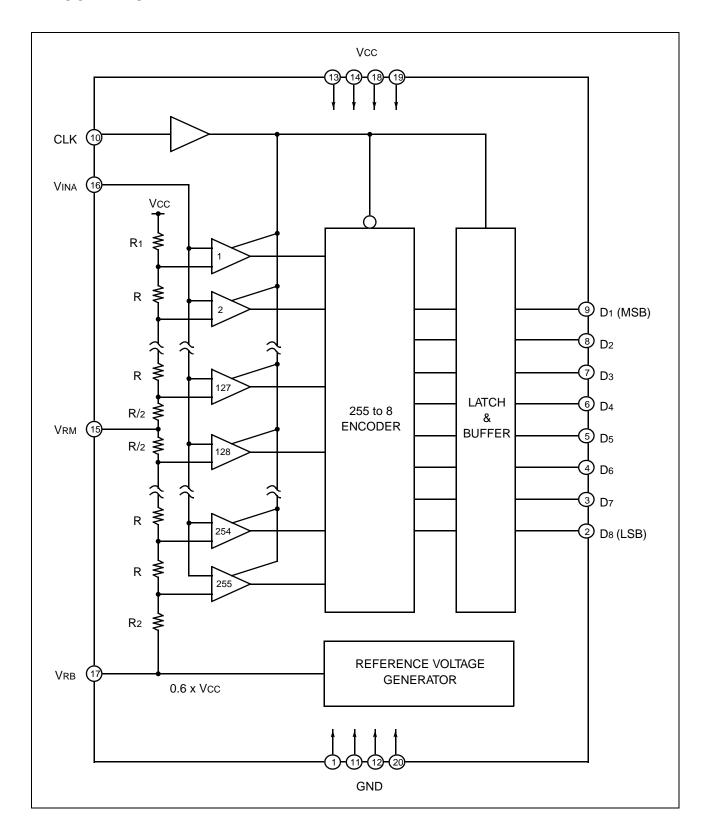
#### **■ PACKAGES**



## **■ PIN ASSIMENT**



## **■ BLOCK DIAGRAM**



# ■ PIN DESCRIPTION

Symbol	Pin No.	Туре	Name & Function		
Power Supp	ly				
Vcc	13, 14, 18, 19	-	+5 V DC power supply pins.		
GND	1, 11, 12, 20	-	Ground pins.		
Clock					
CLK	10	I	Clock input pin. The input voltage is a TTL level.		
Analog Input	t				
VINA	16	I	Analog signal input pin. The analog data to be converted is input to this pin. The input voltage range is 3V to 5V (VRB to VCC).		
Digidal Outp	ut				
D1	9				
D2	8				
D3	7				
D4	6	0	8-bit resolution A/D converter outputs.		
D5	5	O	The output voltage is a TTL level. Also, D1 pin is an MSB and D8 pin is a LSB.		
D6	4				
D7	D7 3				
D8	2				
Refernce Vo	Itage Output				
VRB	17	0	Reference voltage output pin. This pin outputs 0.6 x VCC [V] (T 3V). An $1\mu F$ or more capacitor having superior frequency characteristic should be connected to this pin. The capacitor m be connected near the device.		
Others					
VRM	15	0	An intermediate voltage output pin. An intermediate voltage between VCC and VRB (Typ. 4V) is output from this pin. Normally this pin is left open.		

#### ■ ABSOLUTE MAXIMUM RATINGS

(GND = 0 V)

Parameter	Symbol	Condition	Ra	- Unit	
Parameter	Symbol	Symbol Condition			
Supply Voltage	Vcc	-	-0.5	+7.0	V
Analog Input Voltage	VINA	_	-0.5	Vcc +0.5	V
Digital Input Voltage	VIND	_	-0.5	+7.0	V
Storage Temperature	Tstg	-	-55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

#### ■ RECOMMENDED OPERATING CONDITIONS

(GND = 0 V)

Parameter	Symbol	Condition	Value			Unit	
Farameter	Syllibol	Condition	Min.	Тур.	Max.	Oiiii	
Supply Voltage	Vcc	-	4.75	5.00	5.25	V	
Analog Input Voltage	VINA	-	VRB	_	Vcc	V	
Digital "H" Level Input Voltage	VIHD	_	2.0	_	_	V	
Digital "L" Level Input Voltage	VILD	-	_	_	0.8	V	
Digital "H" Level Output Current	Іон	-	-400	_	_	μΑ	
Digital "L" Level Output Current	lol	_	_	_	1.6	mA	
Clock Frequency	fCLK	-	_	_	60	MHz	
Minimum Clock "H" Level Pulse Width	twH	-	7.0	_	_	ns	
Minimum Clock "L" Level Pulse Width	tw∟	_	8.0	_	_	ns	
Operating Ambient Temperature	Ta	-	-20	_	70	°C	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating conditionranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

## **■ ELECTRICAL CHARACTERISTICS**

## 1. DC CHARACTERISTICS

## (1) Analog Block

Parameter	Symbol Condition		Value			Unit
Farameter	Symbol	Condition	Min.	Тур.	Max.	Jill
Resolution	_	_	_	8	_	bit
Linearity Error	LE	DC Accuracy	_	±0.15	±0.3	%
Differentioal Linearity Error	DLE	DC Accuracy	_	0.12	_	%
Analog Input Equivalent Resister	RINA	-	0.2	1.5	_	МΩ
Analog Input Capacitance	CINA	_	-	40	_	pF
Analog "H" Level Input Current	IIHA	VINA = VCC	_	_	210	μΑ
Analog "L" Level Input Current	IILA	VINA = VREF	-	_	200	μΑ
Reference Voltage	VRB	_	0.6Vcc-0.1	0.6Vcc	0.6Vcc+0.1	V
Supply Current	Icc	_	_	80*	150	mA

<sup>\* :</sup> Vcc = 5.0V, Ta = +25°C

## (2) Digital Block

Parameter	Symbol	ymbol Condition	Value			Unit
Farameter	Syllibol		Min.	Тур.	Max.	Oilit
Digital "H" Level Output Voltage	Vohd	Іон =-400μА	2.7	_	_	V
Digital "L" Level Output Voltage	Vold	IOL = 1.6mA	_	_	0.4	V
Digital "H" Level Input Voltage	VIHD	-	2.0	_	_	V
Digital "L" Level Input Voltage	VILD	_	_	_	0.8	V
Digital "H" Level Input Current	IIHD	_	_	_	20	μΑ
Digital "L" Level Input Current	lild	-	-100	_	_	μΑ

## 2. AC CHARACTERISTICS

Parameter	Symbol	Condition	Value			Unit
raiametei	Syllibol	Condition	Min. Typ. Max.			
Maximum Conversion Rate	fs	_	60	_	_	MSPS
Digital Output Delay Time	tpd	_	5.0	8.5	15	ns

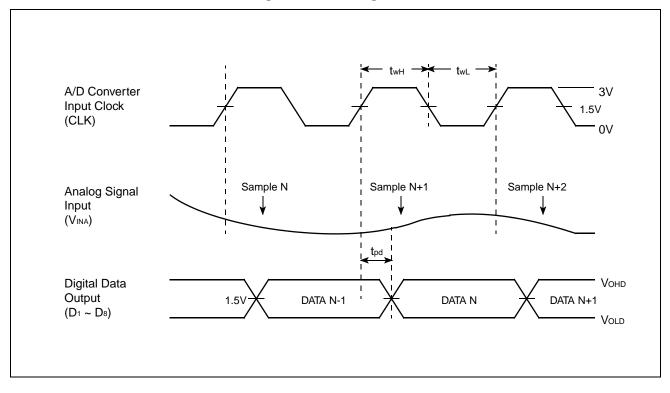
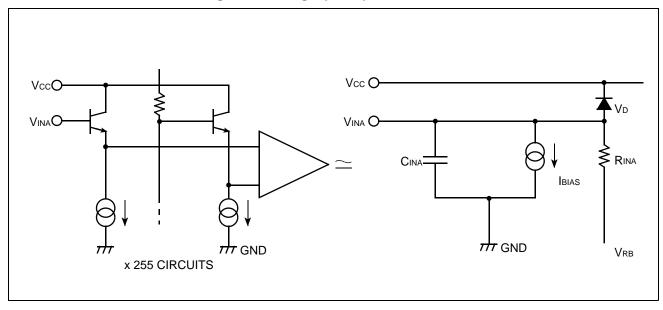


Figure 1. AC Timing Chart

#### **■ EQUIVALENT CIRCUITS**

Figure 2. Analog Input Equivalent Circuit



CINA: Non-linear Emitter-follower Junction Capacitance

RINA: Linear Resistance Model for Input Current Transition by Comparator Switching:

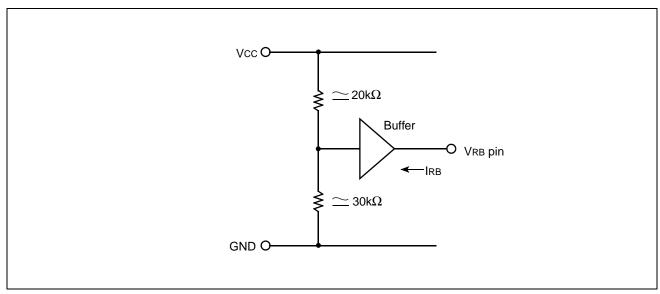
finite value for VINA < VRB or when CLK = "H" level

VRB: Voltage at VRB pin (Not the VRB pin itself)

IBIAS: Constant Input Bias Current

VD: The base-collector junction diode of emitter-follower transistor.

Figure 3. Reference Voltage Circuit



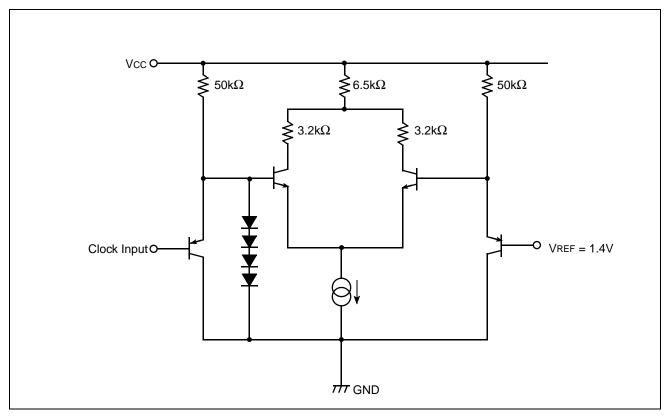
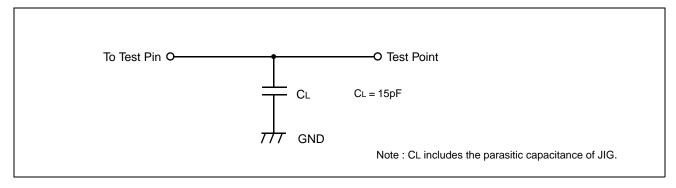


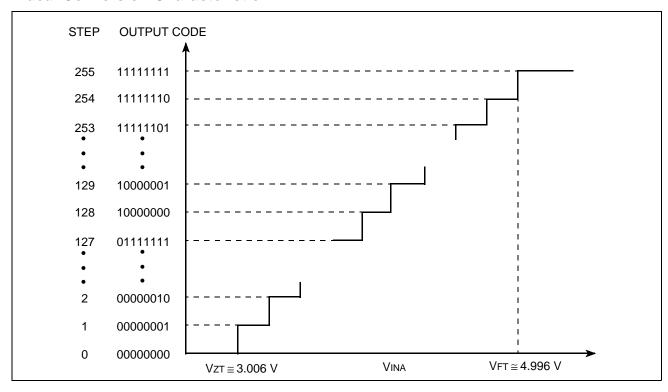
Figure 4. Digital Input Equivalent Circuit

Figure 5. Output Buffer Load Circuit



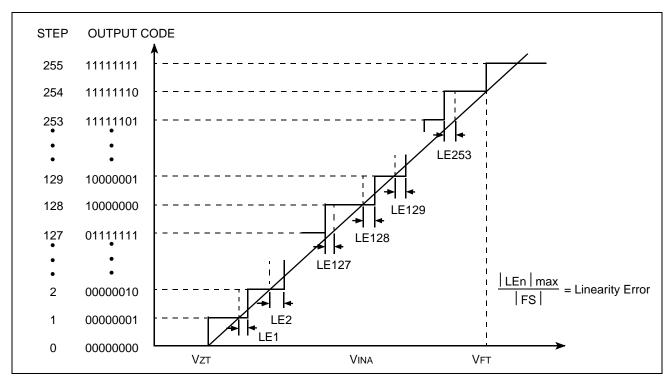
#### **■ LINEARITY ERROR**

#### 1. Ideal Conversion Characteristic



VzT and VFT are the typical values when Vcc = 5 V and VRB = 3 V.

#### 2. Actual Conversion Characteristic



NOTE: Refer to "**ELECTRICAL CHARACTERISTICS**" for a range of VINA inputs.

#### **■ NOTES ON USE**

## 1. Power Supply Patterns of the PCB

The power supply wire patterns (Vcc and GND patterns) of the PCB should be designed as wide as possible in order to reduce parasitic impedance.

Also, the Vcc and GND patterns which are connected to the Vcc and GND pins of the device must be handled and designed as analog system pattern and so, their circuit patterns must be separate from digital system patterns of other peripheral devices.

#### 2. Switching Noise

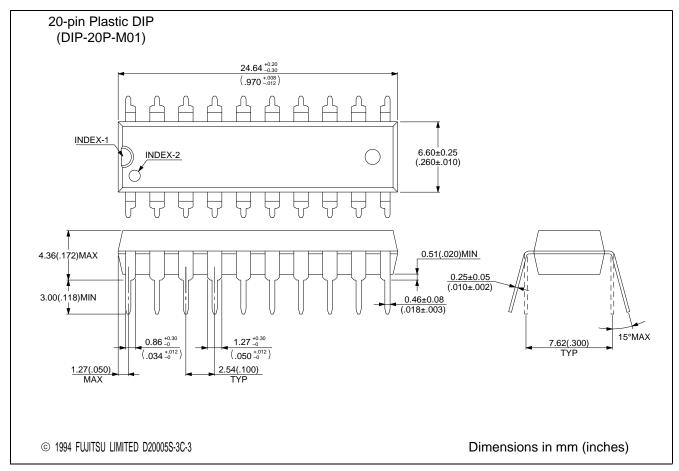
In order to reduce switching noise as much as possible, high-frequency bypass capacitor must be connected between  $V_{CC}$  and GND pins and  $V_{RB}$  and GND pins.

In this case, the capacitor should be connected to the pins as near as possible.

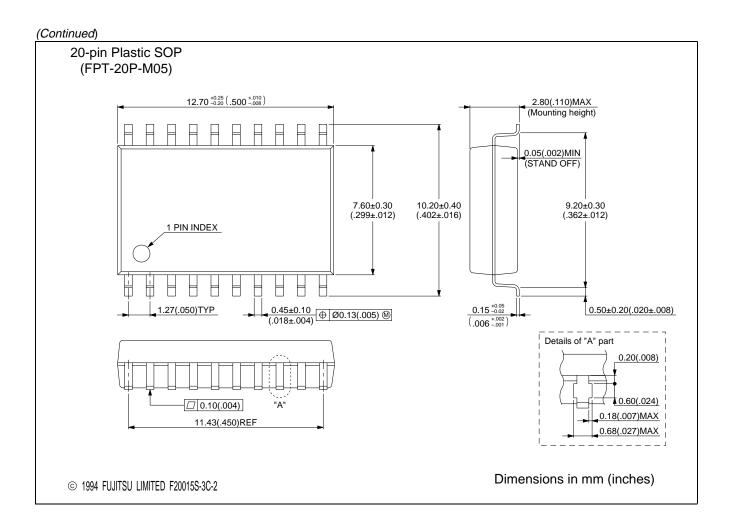
#### ■ ORDERING INFORMATION

Part number	Package	Remarks
MB40528P	20-pin Plastic DIP (DIP-20P-M01)	
MB40528PF	20-pin Plastic SOP (FPT-20P-M05)	

### **■ PACKAGE DIMENSIONS**



(Continued)



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